

Selection Guide

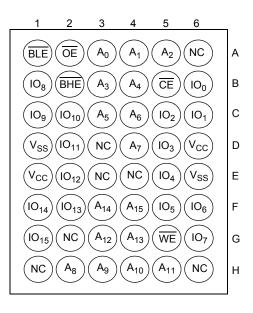
		-8	-10	-12	-15	Unit
Maximum Access Time	8	10	12	15	ns	
Maximum Operating Current	Comm'l/Ind'l	95	90	85	80	mA
	Automotive-A				80	mA
	Automotive-E			90		mA
Maximum CMOS Standby Current	Comm'l/Ind'l	5	5	5	5	mA
	Automotive-A				5	mA
	Automotive-E			10		mA

Pin Configuration

Figure 1. 44-Pin SOJ/TSOP II [1]

A _ Q	
	44 🗋 A ₅
A ₃ □ 2	43 🗖 🗛
A ₂ <u> </u>	42 🗖 🗛
A ₁ <u> </u>	41 🗖 <u>OE</u>
$A_0 \sqsubseteq 5$	40 🗋 BHE
CE C	39 🗌 BLE
IO1 □ 7	38 🗖 IO ₁₆
	37 🗖 IO ₁₅
	36 🗍 10 ₁₄
	35 IO ₁₃
	34 🗆 V _{SS}
V _{SS} [12	$33 \square V_{CC}$
$IO_6 \square 14$	31 IO ₁₂
	30 1 IO ₁₀
	29 🗍 IO ₉
A ₁₅ □ 18	
A	
A	$26 \square A_9$
A	$25 \square A_{10}$
	$24 \square A_{11}$
NC 22	23 🗆 NC

Figure 2. 48-Ball FBGA Pinout ^[1]



Note 1. NC pins are not connected on the die.



Pin Definitions

Pin Name	SOJ, TSOP Pin Number	BGA Pin Number	Ю Туре	Description		
A ₀ -A ₁₅	1–5, 18–21, 24–27, 42–44	A3, A4, A5, B3, B4, C3, C4, D4, H2, H3, H4, H5, G3, G4, F3, F4	Input	Address Inputs. Used to select one of the address locations.		
IO ₁ –IO ₁₆ ^[2]	7–10, 13–16, 29–32, 35–38	B6, C6, C5, D5, E5, F5, F6, G6, B1, C1, C2, D2, E2, F2, F1, G1	Input or Output	ut Bidirectional Data IO lines . Used as input or output lines depend on operation.		
NC	22, 23, 28	A6, D3, E3, E4, G2, H1, H6	No Connect	No Connects. Not connected to the die.		
WE	17	G5	Input or Control	Write Enable Input, Active LOW. When selected LOW, a write is conducted. When deselected HIGH, a read is conducted.		
CE	6	B5	Input or Control	Chip Enable Input, Active LOW. When LOW, selects the chip. When HIGH, deselects the chip.		
BHE, BLE	40, 39	B2, A1	Input or Control	Byte Write Select Inputs, Active LOW . BHE controls $IO_{16} - IO_{9}$, BLE controls $IO_{8} - IO_{1}$.		
ŌĒ	41	A2	Input or Control	Output Enable, Active LOW . Controls the direction of the IO pins. When LOW, the IO pins are allowed to behave as outputs. When deasserted HIGH, the IO pins are tri-stated and act as input data pins.		
V _{SS}	12, 34	D1, E6	Ground	Ground for the device. Connected to ground of the system.		
V _{CC}	11, 33	D6, E1	Power Supply	Power Supply Inputs to the Device.		

Note 2. IO_1-IO_{16} for SOJ/TSOP and IO_0-IO_{15} for BGA packages.



Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage Temperature	
Ambient Temperature with Power Applied55°C to +125°C	
Supply Voltage on V_{CC} Relative to $GND^{[3]}\!0.5V$ to +4.6V	
DC Voltage Applied to Outputs in High Z State $^{[3]}$	
DC Input Voltage $^{[3]}$ 0.5V to V_{CC}+0.5V	
Current into Outputs (LOW) 20 mA	

Static Discharge Voltage	.>2001V
(MIL-STD-883, Method 3015)	

Latch Up Current>200 mA

Operating Range

Range	Ambient Temperature (T _A)	V _{cc}
Commercial	0°C to +70°C	$3.3V\pm10\%$
Industrial	–40°C to +85°C	
Automotive-A	–40°C to +85°C	
Automotive -E	-40°C to +125°C	

Electrical Characteristics

Over the Operating Range

Parameter	Description	Test Conditions		-	8	-10		-1	12	-15		Unit
Farameter	Description				Max	Min	Max	Min	Max	Min	Max	Unit
V _{OH}	Output HIGH Voltage	V _{CC} = Min, I _{OH} = -4.0 mA		2.4		2.4		2.4		2.4		V
V _{OL}	Output LOW Voltage	V _{CC} = Min, I _{OL} = 8.0 mA			0.4		0.4		0.4		0.4	V
V _{IH}	Input HIGH Voltage			2.0	V _{CC} + 0.3	V						
V _{IL}	Input LOW Voltage ^[3]			-0.3	0.8	-0.3	0.8	-0.3	0.8	-0.3	0.8	V
I _{IX}	Input Leakage	$GND \leq V_I \leq V_{CC}$	Com'l/Ind'l	-1	+1	-1	+1	-1	+1	-1	+1	μA
	Current		Auto-A							-1	+1	
			Auto-E					-12	+12			
I _{OZ}	Output Leakage	$GND \leq V_I \leq V_{CC}$,	Com'l/Ind'l	_1	+1	-1	+1	-1	+1	-1	+1	μA
	Current	Output disabled	Auto-A							-1	+1	
			Auto-E					-12	+12			
I _{CC}	V _{CC} Operating	V _{CC} = Max,	Com'l/Ind'l		95		90		85		80	mA
	Supply Current	$I_{OUT} = 0 \text{ mA},$	Auto-A								80	
		$f = f_{MAX} = 1/t_{RC}$	Auto-E						90			
I _{SB1}		<u>Ma</u> x V _{CC} ,	Com'l/Ind'l		15		15		15		15	mA
-	Down Current —TTL	$\overline{CE} \ge V_{IH}$	Auto-A								15	
	Inputs	$V_{IN} \ge V_{IH} \text{ or}$ $V_{IN} \le V_{IL}, \text{ f = f}_{MAX}$	Auto-E						20			
I _{SB2}	Automatic CE Power	<u>Ma</u> x V _{CC} ,	Com'l/Ind'l		5		5		5		5	mA
	Down Current — CMOS Inputs	$\begin{array}{l} CE \geq V_{CC} - 0.3V, \\ V_{IN} \geq V_{CC} - 0.3V, \end{array}$	Auto-A								5	
		or $V_{IN} \le V_{CC} = 0.3V$, f = 0	Auto-E						10			



Capacitance

Tested initially and after any design or process changes that may affect these parameters.

Parameter	Description	Test Conditions	Мах	Unit
C _{IN}	Input Capacitance	$T_A = 25^{\circ}C, f = 1 \text{ MHz}, V_{CC} = 3.3V$	8	pF
C _{OUT}	Output Capacitance		8	pF

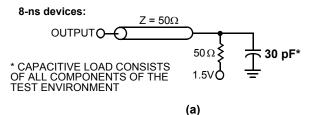
Thermal Resistance

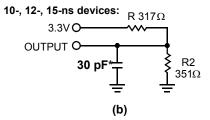
Tested initially and after any design or process changes that may affect these parameters.

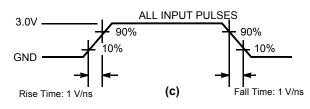
Parameter	Description	Test Conditions	SOJ	TSOP II	FBGA	Unit
Θ_{JA}	· /	Test conditions follow standard test methods and procedures for measuring	65.06	76.92	95.32	°C/W
Θ^{JC}	Thermal Resistance (Junction to Case)	thermal impedance, per EIA/JESD51	34.21	15.86	10.68	°C/W

AC Test Loads and Waveforms

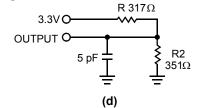
Figure 3. AC Test Loads and Waveforms ^[4]







High-Z characteristics:



Note

4. AC characteristics (except High-Z) for all 8-ns parts are tested using the load conditions shown in Figure (a). All other speeds are tested using the Thevenin load shown in Figure (b). High-Z characteristics are tested for all speeds using the test load shown in Figure (d).



Switching Characteristics

Over the Operating Range [5]

Demonstern	Description	-	8	-10		-12		-15		11
Parameter	Description	Min	Max	Min	Max	Min	Мах	Min	Max	Unit
Read Cycle			1	1	•		1	1	•	
t _{power} [6]	V _{CC} (Typical) to the First Access	100		100		100		100		μs
t _{RC}	Read Cycle Time	8		10		12		15		ns
t _{AA}	Address to Data Valid		8		10		12		15	ns
t _{OHA}	Data Hold from Address Change	3		3		3		3		ns
t _{ACE}	CE LOW to Data Valid		8		10		12		15	ns
t _{DOE}	OE LOW to Data Valid		5		5		6		7	ns
t _{LZOE}	OE LOW to Low Z ^[7]	0		0		0		0		ns
t _{HZOE}	OE HIGH to High Z ^[7, 8]		4		5		6		7	ns
t _{LZCE}	CE LOW to Low Z ^[7]	3		3		3		3		ns
t _{HZCE}	CE HIGH to High Z ^[7, 8]		4		5		6		7	ns
t _{PU} ^[9]	CE LOW to Power Up	0		0		0		0		ns
t _{PD} ^[9]	CE HIGH to Power Down		8		10		12		15	ns
t _{DBE}	Byte Enable to Data Valid		5		5		6		7	ns
t _{LZBE}	Byte Enable to Low Z	0		0		0		0		ns
t _{HZBE}	Byte Disable to High Z		4		5		6		7	ns
Write Cycle ^{[10}	0]									
t _{WC}	Write Cycle Time	8		10		12		15		ns
t _{SCE}	CE LOW to Write End	7		8		9		10		ns
t _{AW}	Address Setup to Write End	7		8		9		10		ns
t _{HA}	Address Hold from Write End	0		0		0		0		ns
t _{SA}	Address Setup to Write Start	0		0		0		0		ns
t _{PWE}	WE Pulse Width	6		7		8		10		ns
t _{SD}	Data Setup to Write End	5		5		6		8		ns
t _{HD}	Data Hold from Write End	0		0		0		0		ns
t _{LZWE}	WE HIGH to Low Z ^[7]	3		3		3		3		ns
t _{HZWE}	WE LOW to High Z ^[7, 8]		4		5		6		7	ns
t _{BW}	Byte Enable to End of Write	6		7		8		9		ns

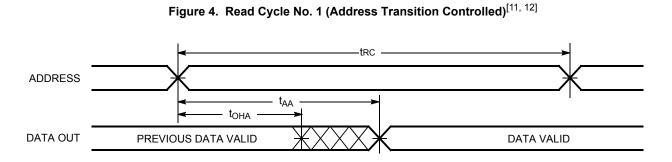
Notes

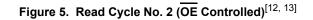
5. Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5V, and input pulse levels of 0 to 3.0V.

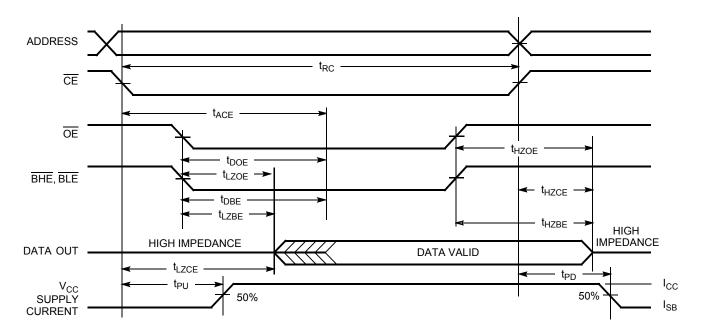
test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5V, and input puise levels of 0 to 3.0V.
 t_{POWER} gives the minimum amount of time that the power supply is at typical V_{CC} values until the first memory access is performed.
 At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE}, t_{HZOE} is less than t_{LZOE}, and t_{HZWE} for any given device.
 t_{HZOE}, t_{HZDE}, t_{HZCE}, and t_{HZWE} are specified with a load capacitance of 5 pF as in part (d) of AC Test Loads and Waveforms. Transition is measured ±500 mV from steady state voltage.
 This parameter is guaranteed by design and is not tested.
 The internal write time of the memory is defined by the overlap of CE LOW, WE LOW, and BHE/BLE LOW. CE, WE, and BHE/BLE is LOW to initiate a write. The transition of these signals terminate the write. The input data setup and hold timing is referenced to the leading edge of the signal that terminates the write.



Switching Waveforms







Notes

11. <u>Device</u> is continuously selected. \overline{OE} , \overline{CE} , \overline{BHE} , and/or $\overline{BLE} = V_{IL}$. 12. WE is HIGH for read cycle.

13. Address valid prior to or coincident with \overline{CE} transition LOW.



Switching Waveforms (continued)

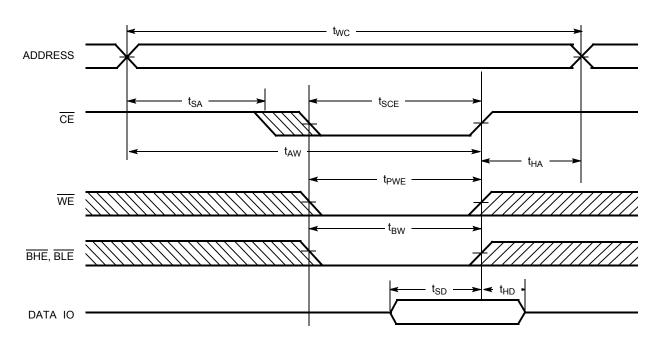
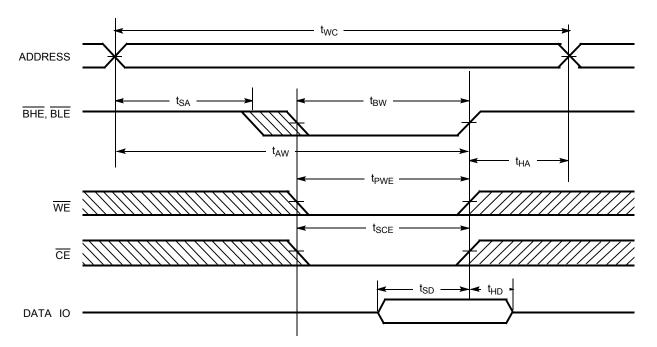


Figure 6. Write Cycle No. 1 (CE Controlled)^[14, 15]

Figure 7. Write Cycle No. 2 (BLE or BHE Controlled)



Notes 14. Data IO is high impedance if OE, BHE, and/or BLE= V_{IH}. 15. If CE goes HIGH simultaneously with WE going HIGH, the output remains in a high impedance state.



Switching Waveforms (continued)

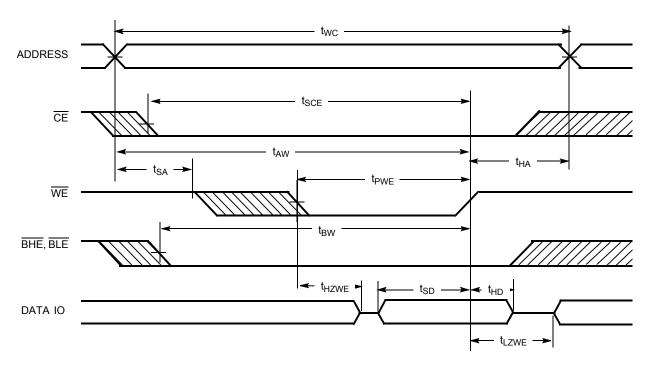


Figure 8. Write Cycle No. 3 (WE Controlled, LOW)

Truth Table

CE	OE	WE	BLE	BHE	10 ₁ -10 ₈	10 ₉ – 10 ₁₆	Mode	Power
Н	Х	Х	Х	Х	High Z	High Z	Power Down	Standby (I _{SB})
L	L	Н	L	L	Data Out	Data Out	Read – All Bits	Active (I _{CC})
			L	Н	Data Out	High Z	Read – Lower Bits Only	Active (I _{CC})
			Н	L	High Z	Data Out	Read – Upper Bits Only	Active (I _{CC})
L	Х	L	L	L	Data In	Data In	Write – All Bits	Active (I _{CC})
			L	Н	Data In	High Z	Write – Lower Bits Only	Active (I _{CC})
			Н	L	High Z	Data In	Write – Upper Bits Only	Active (I _{CC})
L	Н	Н	Х	Х	High Z	High Z	Selected, Outputs Disabled	Active (I _{CC})
L	Х	Х	Н	Н	High Z	High Z	Selected, Outputs Disabled	Active (I _{CC})



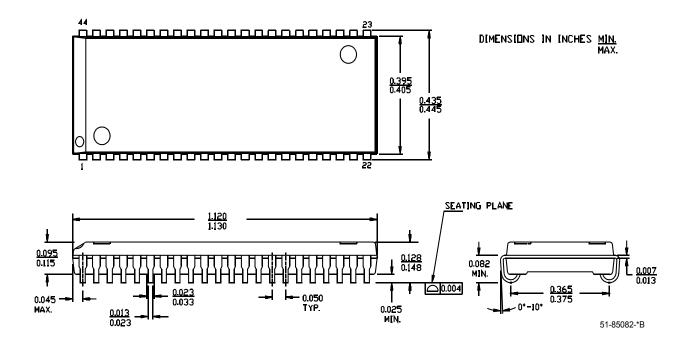
Ordering Information

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
8	CY7C1021CV33-8VXC	51-85082	44-pin (400-Mil) Molded SOJ (Pb-free)	Commercial
	CY7C1021CV33-8ZXC		44-pin TSOP Type II (Pb-free)	
	CY7C1021CV33-8BAXC	51-85096	48-ball FBGA (Pb-free)	
10	CY7C1021CV33-10VC	51-85082	44-pin (400-Mil) Molded SOJ	Commercial
	CY7C1021CV33-10VXC		44-pin (400-Mil) Molded SOJ (Pb-free)	
	CY7C1021CV33-10ZXC	51-85087	44-pin TSOP Type II (Pb-free)	
	CY7C1021CV33-10ZI	51-85087	44-pin TSOP Type II	Industrial
	CY7C1021CV33-10ZXI		44-pin TSOP Type II (Pb-free)	
	CY7C1021CV33-10BAXI	51-85096	48-ball FBGA (Pb-free)	
12	CY7C1021CV33-12VC	51-85082	44-pin (400-Mil) Molded SOJ	Commercial
	CY7C1021CV33-12VXC		44-pin (400-Mil) Molded SOJ (Pb-free)	
	CY7C1021CV33-12ZXC	51-85087	44-pin TSOP Type II (Pb-free)	
	CY7C1021CV33-12VI	51-85082	44-pin (400-Mil) Molded SOJ	Industrial
	CY7C1021CV33-12VXI		44-pin (400-Mil) Molded SOJ (Pb-free)	
	CY7C1021CV33-12ZXI	51-85087	44-pin TSOP Type II (Pb-free)	
	CY7C1021CV33-12BAI	51-85096	48-ball FBGA	
	CY7C1021CV33-12BAXI		48-ball FBGA (Pb-free)	
	CY7C1021CV33-12VE	51-85082	44-pin (400-Mil) Molded SOJ	Automotive-E
	CY7C1021CV33-12VXE		44-pin (400-Mil) Molded SOJ (Pb-free)	
	CY7C1021CV33-12ZSE	51-85087	44-pin TSOP Type II	
	CY7C1021CV33-12ZSXE		44-pin TSOP Type II (Pb-free)	
	CY7C1021CV33-12BAE	51-85096	48-ball FBGA	
15	CY7C1021CV33-15VXC	51-85082	44-pin (400-Mil) Molded SOJ (Pb-free)	Commercial
	CY7C1021CV33-15ZXC	51-85087	44-pin TSOP Type II (Pb-free)	
	CY7C1021CV33-15ZI	51-85087	44-pin TSOP Type II	Industrial
	CY7C1021CV33-15ZXI		44-pin TSOP Type II (Pb-free)	
	CY7C1021CV33-15BAXI	51-85096	48-ball FBGA (Pb-free)	
	CY7C1021CV33-15ZSXA	51-85087	44-pin TSOP Type II (Pb-free)	Automotive-A



Package Diagrams

Figure 9. 44-Pin (400 Mil) Molded SOJ

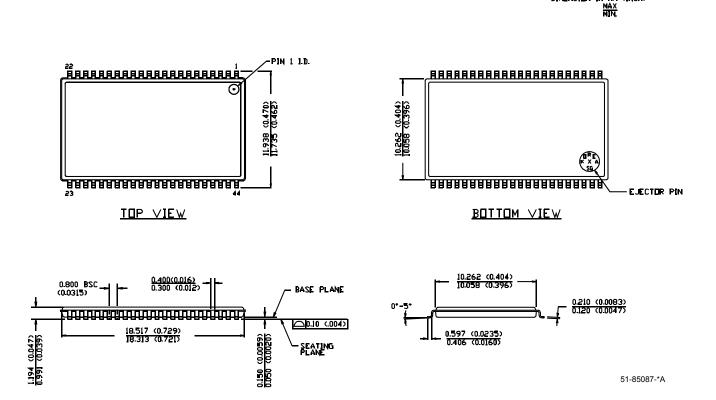




DIMENSION IN MM (INCH)

Package Diagrams (continued)

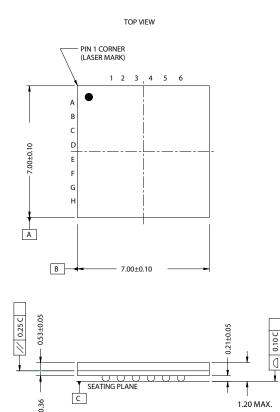
Figure 10. 44-Pin Thin Small Outline Package Type II

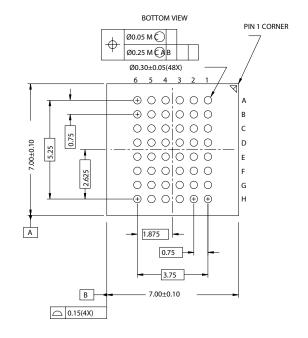




Package Diagrams (continued)

Figure 11. 48-Ball FBGA (7 x 7 x 1.2 mm)





51-85096-*G



Document History Page

REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	109472	12/06/01	HGK	New datasheet
*A	115044	05/08/02	HGK	Ram7 version C4K x 16 Async Removed "Preliminary"
*B	115808	06/25/02	HGK	I _{SB1} and I _{CC} values changed
*C	120413	10/31/02	DFP	Updated BGA pin E4 to NC
*D	238454	See ECN	RKF	 Added Automotive Specifications to datasheet Added Pb-free devices in the Ordering Information
*E	334398	See ECN	SYT	Added Pb-free on page 9 and 10
*F	493565	See ECN	NXR	Added Automotive-A operating range Corrected typo in the Pin Definition table Changed the description of I _{IX} from Input Load Current to Input Leakage Current in DC Electrical Characteristics table Removed I _{OS} parameter from DC Electrical Characteristics table Updated the ordering information table
*G	563963	See ECN	VKN	Added t _{POWER} specification in the AC Switching Characteristics table Added footnote 8
*H	1390863	See ECN	VKN/AESA	Corrected TSOP II package outline

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